

	L #	Hits	Search Text	DBs	Time Stamp
1	L1	24	("20030026989" "20030059633" "5562998" "5855753" "5998003" "6103386" "6203613" "6203927" "6416870" "6492038" "6503330" "6585823").PN. <i>from IDS (1/16/04)</i>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 13:53
2	L2	20562	(427/566,567,569-577,595,596,597,248.1-255.7).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:00
3	L3	4263	(427/567,570,576,585,597,249.15,249.17,255.29,255.31,255.32,255.394).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:00
4	L4	21217	(427/566,567,569-577,585,595,596,597,248.1-255.7).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:01
5	L5	68409	(ALD (atomic Mono) near (layer deposit deposition) monolayer atomiclayer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:04
6	L6	1903	((Tantalum Ta) adj (oxide pentoxide) Ta2O5 "Ta.sub.2O.sub.5" "Ta.sub.2O.sub.5") with (grain crystal\$7 column columnar orient\$7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:07
7	L7	3980	((Tantalum Ta) adj (oxide pentoxide) Ta2O5 "Ta.sub.2O.sub.5" "Ta.sub.2O.sub.5") same (grain crystal\$7 column columnar orient\$7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:08

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	L #	Hits	Search Text	DBs	Time Stamp
L24 L25	8	L8 16	((Tantalum Ta) adj (oxide pentoxide) Ta2O5 "Ta.sub.2O.sub.5" "Ta.sub.2O.sub.5") with (grain crystal\$7) near5 (column columnar)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:09
	9	L9 2455937	(Silicon Si siliconnitride siliconcarbide "SiN.m/c." SiC Si3N4 "Si.sub.x C" "Si.sub.3N.sub.4" "Si.sub.3N.sub.4" "Si.sub.xN.sub.y" "Si.sub.x N.sub.y")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:16
L16	10	L10 5	L9 same L8 L10 not L16 → 46/3 L31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:14
	11	L11 1604	L9 same L7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:14
	12	L12 652	L9 same L6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:15
	13	L13 2204	L5 same ((Silicon Si) adj (carbide nitride) siliconnitride siliconcarbide "SiN.m/c." SiC Si3N4 "Si.sub.x C" "Si.sub.3N.sub.4" "Si.sub.3N.sub.4" "Si.sub.xN.sub.y" "Si.sub.x N.sub.y" oxycarbide carbonitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:16
	14	L14 3392	L5 same (alumina hafnia (aluminum Al hafnium Hf) adj (oxide dioxide) Al2O3 HfO2 "Al.sub.2O.sub.3" "HfO.sub.2" "Al.sub.2 O.sub.3")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:20

	L #	Hits	Search Text	DBs	Time Stamp
15	L15	0	L10 same (L13 or L14)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:22
16	L16	1	L10 and (L13 or L14) <i>fluoride pre-pub 2005/0158570A1</i>	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:21
17	L17	0	L8 and (L13 or L14) not L16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:21
18	L18	5	L12 same (L13 or L14) not L16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:22
19	L19	32	L12 and (L13 or L14) not (L16 or L18)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:23
20	L20	17	L11 same (L13 or L14) not (L16 or L18 or L19)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:23
21	L21	53	L11 and (L13 or L14) not (L16 or L18 or L19 or L20)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:25

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L29

	L #	Hits	Search Text	DBs	Time Stamp
22	L22	1	L8 and L5 and L4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:25
23	L23	0	L8 and L5 and L4 (not L16)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:26
24	L24	1	L8 and L4 not L16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:26
25	L25	14	L8 not (L16 or L24)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:28
26	L26	0	L19 and L4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:28
27	L27	0	L20 and L4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:28
28	L28	2	L21 and L4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:28

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	L #	Hits	Search Text	DBs	Time Stamp
29	L29	51	L21 not L28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:29
30	L30	14	((("5100847") or ("6159553") or ("6582779") or ("6350404") or ("6699604") or ("6861164") or ("6887594"))).PN. <i>from inventor name search</i>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:38

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	L #	Hits	Search Text	DBs	Time Stamp
29	L19	32	L12 and (L13 or L14) not (L16 or L18)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 16:07
30	L20	17	L11 same (L13 or L14) not (L16 or L18 or L19)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 17:17
31	L29	51	L21 not L28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 18:48
32	L32	70	L7 same (EBPDV EB (E electron) adj beam)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 18:51
33	L33	32	L32 and (L11 or L12)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 18:51
34	L34	30	L33 not (L16 or L18 or L19 or L20 or L28 or L29)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 18:53

Day : Saturday
Date: 6/17/2006


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Time: 14:33:29

Inventor Name Search Result

Your Search was:

Last Name = LI

First Name = CHIEN-WEI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
07297530	Not Issued	161	01/17/1989	SUPER TOUGH MONOLITHIC SILICON NITRIDE DESCRIPTION OF THE INVENTION	LI, CHIEN-WEI
07450899	Not Issued	161	12/14/1989	SUPER TOUGH MONOLITHIC SILICON NITRIDE	LI, CHIEN-WEI
07576330	Not Issued	166	08/31/1990	SUPER TOUCH MONOLITHIC SILICON NITRIDE	LI, CHIEN-WEI
07716142	Not Issued	166	06/17/1991	HIGH TOUGHNESS-HIGH STRENGTH SINTERED SILICON NITRIDE	LI, CHIEN-WEI
07759970	5100847	150	09/17/1991	SUPER TOUGH MONOLITHIC SILICON NITRIDE	LI, CHIEN-WEI
07860958	Not Issued	166	03/31/1992	MONOLITHIC SILICON NITRIDE HAVING HIGH FRACTURE TOUGHNESS	LI, CHIEN-WEI
07865581	Not Issued	166	04/09/1992	SINTERED SILICON NITRIDE OF HIGH TOUGHNESS, STRENGTH AND RELIABILITY	LI, CHIEN-WEI
08075930	Not Issued	161	06/14/1993	MONOLITHIC SILICON NITRIDE HAVING HIGH FRACTURE TOUGHNESS	LI, CHIEN-WEI
08076940	5312788	150	06/16/1993	HIGH TOUGHNESS, HIGH STRENGTH SINTERED SILICON NITRIDE	LI, CHIEN-WEI
08096203	5637540	150	07/23/1993	SINTERED SILICON NITRIDE OF HIGH TOUGHNESS, STRENGTH AND RELIABILITY	LI, CHIEN-WEI
08168439	5449649	150	12/17/1993	MONOLITHIC SILICON NITRIDE HAVING HIGH FRACTURE TOUGHNESS	LI, CHIEN-WEI

<u>08257598</u>	<u>5494866</u>	150	06/09/1994	STRESS-RUPTURE RESISTANT SINTERED SILICON NITRIDE	LI, CHIEN-WEI
<u>08789699</u>	<u>5759933</u>	150	01/27/1997	GAS PRESSURE SINTERED SILICON NITRIDE HAVING HIGH STRENGTH AND STRESS RUPTURE RESISTANCE	LI, CHIEN-WEI
<u>09208109</u>	<u>6159553</u>	150	11/27/1998	THERMAL BARRIER COATING FOR SILICON NITRIDE	LI, CHIEN-WEI
<u>09371826</u>	<u>6582779</u>	150	08/11/1999	SILICON NITRIDE COMPONENTS WITH PROTECTIVE COATING	LI, CHIEN-WEI
<u>09592320</u>	<u>6350404</u>	150	06/13/2000 ?	Method for producing a ceramic part with an internal structure	LI, CHIEN-WEI
<u>09595791</u>	<u>6415376</u>	150	06/16/2000 ?	APPARATUS AND METHOD FOR ISSUE GROUPING OF INSTRUCTIONS IN A VLIW PROCESSOR	LI, CHIEN-WEI
<u>09598015</u>	<u>6699604</u>	150	06/20/2000 ?	PROTECTIVE COATING INCLUDING POROUS SILICON NITRIDE MATRIX AND NOBLE METAL	LI, CHIEN-WEI
<u>09990640</u>	<u>6861164</u>	150	11/21/2001	ENVIRONMENTAL AND THERMAL BARRIER COATING FOR CERAMIC COMPONENTS	LI, CHIEN-WEI
<u>10085437</u>	<u>6684320</u>	150	02/28/2002 ?	APPARATUS AND METHOD FOR ISSUE GROUPING OF INSTRUCTIONS IN A VLIW PROCESSOR	LI, CHIEN-WEI
<u>10085724</u>	Not Issued	93	02/28/2002 X	AREA AND POWER EFFICIENT VLIW PROCESSOR WITH IMPROVED SPEED	LI, CHIEN-WEI
<u>10621168</u>	<u>6977233</u>	150	07/15/2003 X	SINTERED SILICON NITRIDE	LI, CHIEN-WEI
<u>10621719</u>	Not Issued	161 abd	07/16/2003	Environmental & thermal barrier coating	LI, CHIEN-WEI
<u>10644523</u>	Not Issued	71	08/18/2003	Diffusion barrier coating for si-based components	LI, CHIEN-WEI
<u>10682752</u>	Not Issued	93 Allor	10/08/2003	BRAZE-BASED PROTECTIVE COATING FOR SILICON NITRIDE	LI, CHIEN-WEI
<u>10719629</u>	Not Issued	71	11/21/2003	Oxidation barrier coatings for silicon based ceramics	LI, CHIEN-WEI
<u>10759810</u>	Not Issued	71	01/16/2004	Atomic layer deposition for turbine components	LI, CHIEN-WEI

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<u>10773373</u>	<u>6887594</u>	150	02/05/2004	ENVIRONMENTAL AND THERMAL BARRIER COATING FOR CERAMIC COMPONENTS	LI, CHIEN-WEI
<u>10982445</u>	Not Issued	30	11/05/2004	Protective coating for ceramic components	LI, CHIEN-WEI
<u>11127522</u>	Not Issued	30	05/10/2005	Ternary carbide and nitride materials having tribological applications and methods of making same	LI, CHIEN-WEI
<u>11127524</u>	Not Issued	30	05/10/2005	Ternary carbide and nitride composites having tribological applications and methods of making same	LI, CHIEN-WEI
<u>11216877</u>	Not Issued	30	08/30/2005	Sintered silicon nitride	LI, CHIEN-WEI
<u>60278102</u>	Not Issued	159	03/23/2001	Environmental and thermal barrier coating for ceramic components	LI, CHIEN-WEI
<u>60575040</u>	Not Issued	159	05/26/2004	Ternary metal carbides-silver composite materials for tribological applications	LI, CHIEN-WEI
<u>60575041</u>	Not Issued	159	05/26/2004	Novel carbide materials for tribological applications	LI, CHIEN-WEI
<u>60740172</u>	Not Issued	20	11/28/2005	Ruthenium precursors and intermediates for deposition processes, their production and method of use	LI, CHIEN-WEI
<u>60740206</u>	Not Issued	20	11/28/2005	Ruthenium precursors and intermediates for plasma-enhanced ALD	LI, CHIEN-WEI

Prepubs

Inventor Search Completed: No Records to Display.

	Last Name	First Name
Search Another: Inventor	<input type="text" value="LI"/>	<input type="text" value="CHIEN-WEI"/> <input type="button" value="Search"/>

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